

DATASHEET



SensL's Second Generation of Red-Enhanced Silicon Photomultipliers

MicroRB sensors are the second release of Silicon Photomultipliers (SiPM) from SensL's R-Series range. The MicroRB sensors provide further sensitivity improvements in the red and NIR region of the electromagnetic spectrum. All R-Series SiPM sensors feature high responsivity, fast signal response and a low temperature coefficient of operating voltage, all achieved at a low bias voltage. The sensor is packaged in a compact and robust MLP (molded lead frame) package that is suitable for reflow solder processes. Both the sensor and the package are designed for volume production with the product delivered on tape and reel.

SiPM sensors are an improvement over avalanche photodiodes (APD) and PIN diodes due to their high gain and single photon sensitivity. This enables the detection of low reflectivity targets at very long distance in LiDAR applications. Unlike the similarly-operated SPAD that can *only* detect single photons, the SiPM overcomes this limitation by incorporating a 'microcell' structure that allows for multi-photon detection with a high dynamic range. It is strongly recommended that those new to SiPM sensors consult the Introduction to Silicon Photomultipliers Tech Note.

GENERAL PARAMETERS

Parameter ¹	Microcell Size	Minimum	Typical	Maximum	Units
	10 μm		27.1		V
Breakdown Voltage (Vbr) 2,3	20 μm		23.2		
	35 μm		23.0		
Breakdown Voltage Range 4			± 0.5		V
Overvoltage (Vov) ^{2, 4}	10 μm		20	20	
	20 μm		10	15	V
	35 μm		7	10	
Spectral Range 5		300		1050	nm

¹ All measurements made at 21 °C unless otherwise stated.

current and V is the bias voltage.

PHYSICAL PARAMETERS

Parameter	10010	10020	10035
Active area		1 mm x 1 mm	
Microcell size	10 μm x 10 μm	20 μm x 20 μm	35 μm x 35 μm
Number of microcells	4296	1590	620
Microcell fill factor	43 %	63 %	76 %

² Operating bias (Vbias) = Vbr + Vov

 $^{^3}$ The breakdown voltage (Vbr) is defined as the value of the voltage intercept of a straight line fit to a plot of $\surd l$ vs V, where l is the

⁴ For a given lot. Specific information is given in the lot Release Note. Contact SensL Sales for information.

⁵ Range at which the maximum PDE is >1%.





PERFORMANCE PARAMETERS

Parameter ⁶	10010	10020	10035	Units
PDE @ 905 nm @ maximum overvoltage 7,8	4.0	7.3	10.3	%
PDE @ 905 nm @ typical overvoltage 6, 7	4.0	5.6	9.1	%
Responsivity @ 905 nm @ maximum overvoltage 8	52	270	420	kA/W
Responsivity @ 905 nm @ typical overvoltage 6	52	61	240	kA/W
Gain - cathode-anode output ⁶	0.7×10^6	0.9×10^6	1.7×10^6	
Dark count rate 6,9	2.5	2.7	3.8	MHz
Dark current ⁶	0.52	0.54	1.5	μΑ
Rise time - standard output 6,10	1.5	1.0	0.9	ns
Microcell recharge time constant 6, 10, 11	12	21	73	ns
Rise time - fast output 6, 10	490	490	490	ps
Fast output pulse width (FWHM) 6, 10	2.3	2.0	3.7	ns
Crosstalk ⁶	30	22	33	%
Afterpulsing ⁶	13	6	1	%
Excess noise factor ⁶	1.34	1.19	1.22	
Temperature coefficient of Vbr		See page 4		

⁶ All measurements made at 21°C and 'Typical' overvoltage (see page 1) unless otherwise specified.

PACKAGE PARAMETERS

Parameter	10010	10020	10035	
Package dimensions	1.5 mm x 1.8 mm			
Soldering conditions	Lead-free, reflow soldering process compatible See the SMT Handling Tech Note for more details.			
Encapsulant type	Clear transfer molding compound			
Encapsulant refractive index	1.57 @ 589 nm			
Moisture sensitivity level (MSL)	MSL 3 for tape & reel (TR) MSL 4 for tape only (TA)			

ABSOLUTE MAXIMUM RATINGS

	10010	10020	10035	
Maximum current	3 mA			
Recommended operating temperature range		-40 °C - +85 °C		
Maximum storage temperature		105 °C		

⁷ PDE (Photon Detection Efficiency) is the product of the QE *AIP*FF, where QE is quantum efficiency, AIP is the avalanche initiation probability and FF is the fill factor of the microcells.

⁸ Measured at maximum overvoltage.

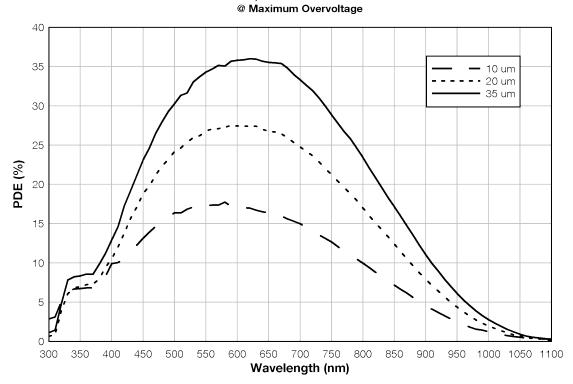
⁹ Each thermally generated 'noise' carrier in the active volume of the sensor will generate a signal equal to that of a single photon. The rate of these spurious counts is referred to as the dark count rate.

¹⁰ All timing measurements acquired using a SensL SMA board, see page 6. $\,^{11}$ RC charging time constant of the microcell (τ).

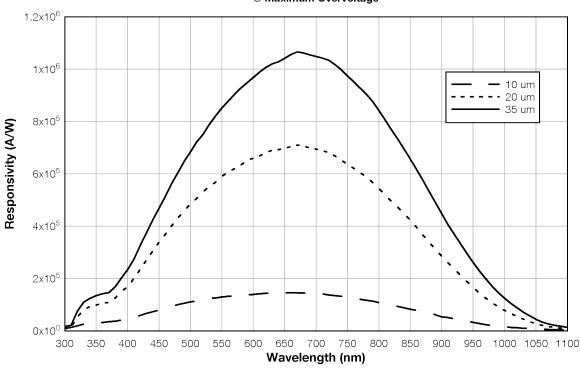


PERFORMANCE PLOTS

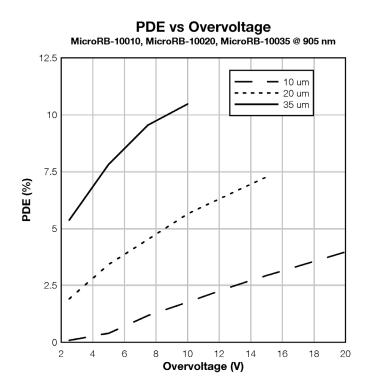
PDE vs Wavelength MicroRB-10010, MicroRB-10020. MicroRB-10035

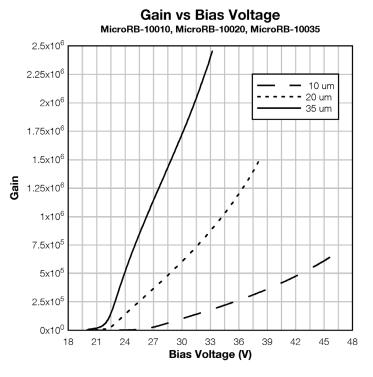


Responsivity vs Wavelength
MicroRB-10010, MicroRB-10020. MicroRB-10035 @ Maximum Overvoltage









Temperature Coefficient of Breakdown Voltage

The RB-Series breakdown voltage has a non-linear relationship with temperature. The plots below show typical behavior for each microcell size. Please contact SensL Sales for more infromation.

Breakdown Voltage vs Temperature

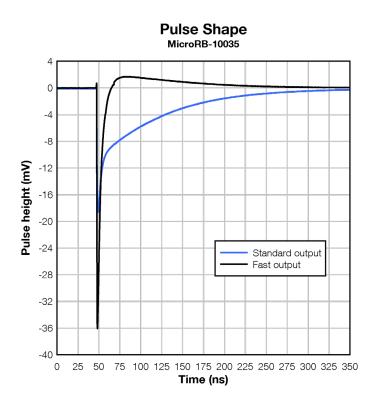
MicroRB-10010, MicroRB-10020, MicroRB-10035 45 40 10um 20um - 35um Breakdown Voltage (V) 25 20 15 -40 -20 40 80 100 120 Temperature (°C)

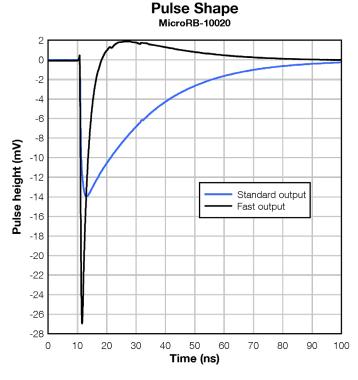


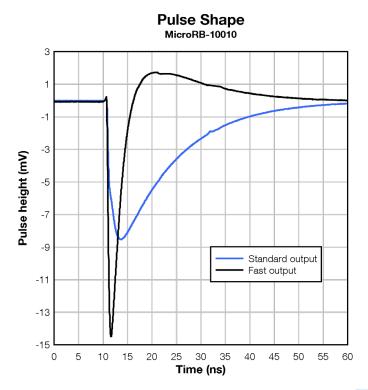


Pulse Shape

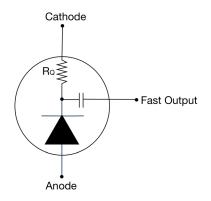
The measurement of the pulse shapes below were acquired using a SensL SMA board (see page 6) with a 50 ps pulse from a 420 nm laser. The laser was set-up to activate approximately 10 - 15 % of the microcells simultaneously.







NOTE: MicroRB sensors use an N-on-P diode and therefore have a different fast pulse polarity compared to SensL P-on-N sensors i.e. C-Series, although the pin-out is the same.





EVALUATION BOARDS

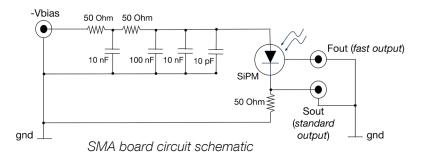
SMA BIASING BOARD (MicroRB-SMA-100XX)

The MicroRB-SMA is a printed circuit board (PCB) that can facilitate the evaluation of the MicroRB MLP sensors. The board has three female SMA connectors for connecting the bias voltage, the standard output from the cathode and the fast output signal. The output signals can be connected directly to a 50Ω -terminated oscilloscope for viewing. The biasing and output signal tracks are laid out in such a way as to preserve the fast timing characteristics of the sensor.

The MicroRB-SMA is recommended for users who require a plugand-play set-up to quickly evaluate MicroRB sensors with optimum timing performance. The board also allows the signal from the cathode-anode readout to be observed at the same time as the fast output. The outputs can be connected directly to the oscilloscope or measurement device, but external preamplification may be required to boost the signal. The table below lists the SMA board connections. The SMA board electrical schematics are available to download in the Board Reference Design document.



MicroRB-SMA-100XX			
Output Function			
Vbias	negative bias input (anode)		
Fout	fast output		
Sout	standard output (cathode)		

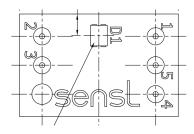


PIN ADAPTER BOARD (MicroRB-SMTPA-100XX)

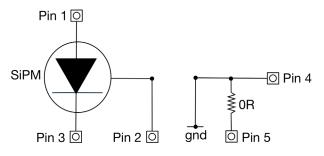
The Pin Adapter board (SMTPA) is a small PCB board that houses the SIPM sensor and has through-hole pins to allow its use with standard sockets or probe clips. This product is useful for those needing a quick way to evaluate the MLP-packaged sensor without the need for specialist surface-mount soldering. While this is a 'quick

fix' suitable for many evaluations, it should be noted that the timing performance from this board will not be optimized and if the best possible timing performance is required, the MicroRB-SMA-100XX is recommended. The SMTPA circuit schematic is shown below. Please consult the MicroRB User Manual for further information on biasing. The SMTPA board electrical schematics are available to download in the Board Reference Design document.





Top view of the SMTPA board showing the pin numbering



SMTPA board circuit schematic

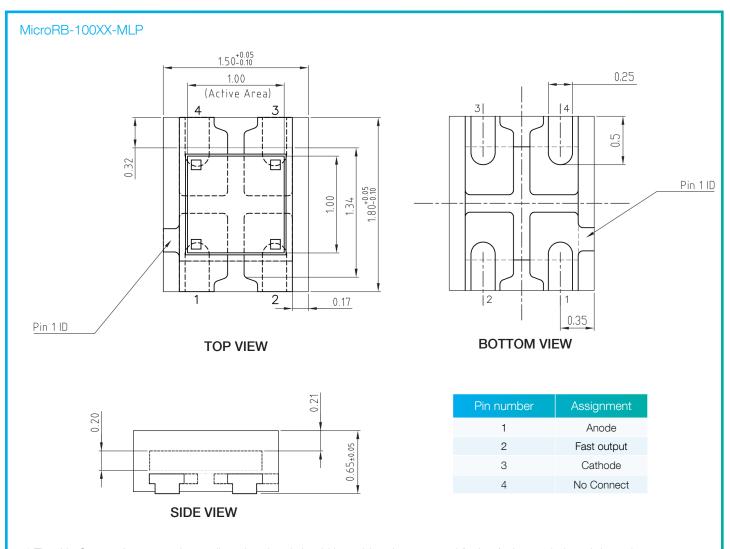
MicroRB-SMTPA-100XX			
Pin No.	Connection		
1	anode		
2	fast output		
3	cathode		
4	ground		
5	ground		







PRODUCT DRAWINGS (all dimensions in mm)

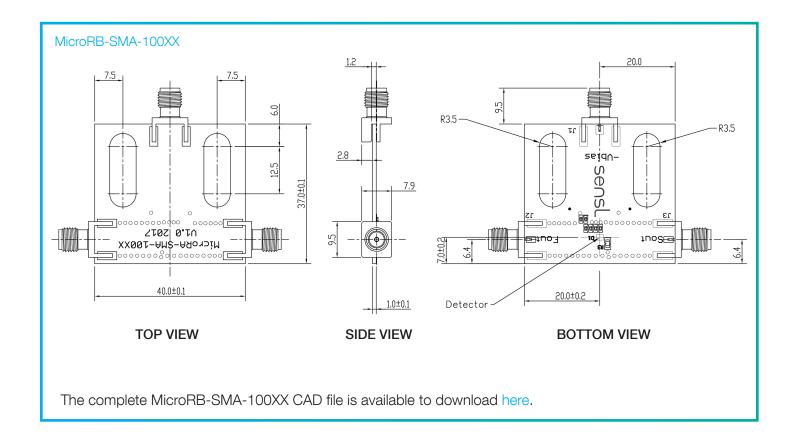


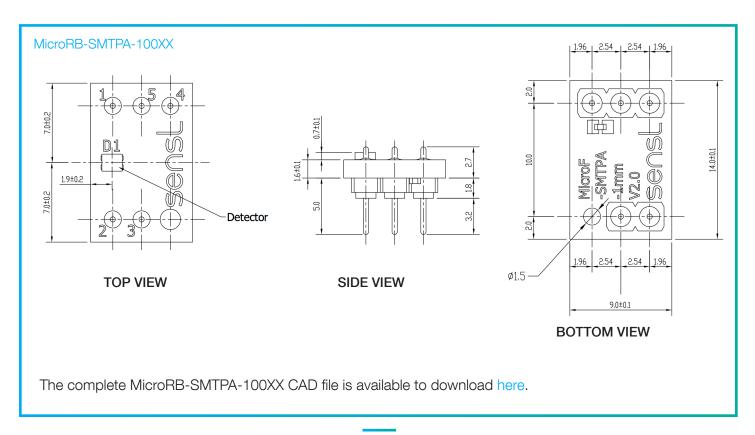
^{*} The 'No Connect' pins are electrically isolated and should be soldered to a ground (or bias) plane to help with heat dissipation.

The CAD file for the MicroRB-100XX-MLP package and tape and reel, and the solder footprint is available to download here.













USEFUL LINKS

- Introduction to Silicon Photomultipliers Tech Note If you are new to SiPM, this document explains their operation and main performance parameters.
- Biasing and Readout Tech Note This document gives detailed information on how to bias the sensor for both standard and fast configurations, and amplifying and reading out the signal.
- How to Evaluate and Compare Silicon Photomultipliers Tech Note Information on what to consider when selecting an SiPM.
- Handling and Soldering Guide This document gives information on safe handling of the sensors and soldering to PCB.
- SensL Website for more information on all of SensL's products as well as application information.
- CAD file library SensL CAD files include solder footprints and tape and reel information.
- 3D drawing library 3D files for SensL products can be downloaded as SolidWorks, STEP and Inventor files.







ORDERING INFORMATION

Product Code	Microcell size	Sensor active area	Package description	Delivery option ^a
MicroRB-10010-MLP			4-side tileable, surface mount, molded leadframe package (MLP)	GP
MicroRB-SMA-10010	10 μm		MLP sensor mounted onto a PCB with SMA connectors for bias and output.	PK
MicroRB-SMTPA-10010			MLP packaged sensor mounted onto a pin adapter board.	PK
MicroRB-10020-MLP			4-side tileable, surface mount, molded leadframe package (MLP)	TA, TR
MicroRB-SMA-10020	20 μm	1 x 1 mm ²	MLP sensor mounted onto a PCB with SMA connectors for bias and output.	PK
MicroRB-SMTPA-10020			MLP packaged sensor mounted onto a pin adapter board.	PK
MicroRB-10035-MLP			4-side tileable, surface mount, molded leadframe package (MLP)	TA, TR
MicroRB-SMA-10035	35 μm		MLP sensor mounted onto a PCB with SMA connectors for bias and output.	PK
MicroRB-SMTPA-10035			MLP packaged sensor mounted onto a pin adapter board.	PK

For information on the availability of automotive qualified versions of these parts, please contact sales@sensl.com

PK = ESD Package TA = Tape TR = Tape and Reel

GP = Gel Pack

There is a minimum order quantity (MOQ) of 3000 for the tape and reel (TR) option. Quantities less than this are available on tape (-TA) which will ship according to the table below:

		-TR	
Sensor size	Cut tape (no reel)	Tape loaded onto a generic reel *	Tape & reel MOQ **
1mm	<50	50 - 3000	3000

^{*} Details of the generic reel can be found here.

^a The two-letter delivery option code should be appended to the order number, e.g.) to receive a MicroRB-10035-MLP on cut tape, use MicroRB-10035-MLP-TA. The codes are as follows:

^{*} The TR option is only available in multiples of the MOQ.

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AR0234CSSC00SUKAH3-GEVB AR0130CSSM00SPCAH-GEVB AR0330CM1C00SHAAH3-GEVB EVALZ-ADPD2212 TMD2772EVM
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